TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74HC4075AP, TC74HC4075AF

#### TRIPLE 3-INPUT OR GATE

The TC74HC4075A is a high speed CMOS 3-INPUT OR GATE fabricated with silicon gate  $C^2MOS$  technology.

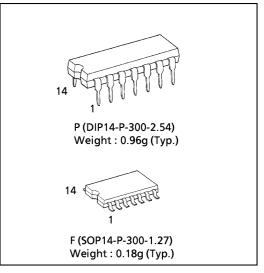
It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 4 stages including a buffered outputs, which provide high noise immunity and stable output.

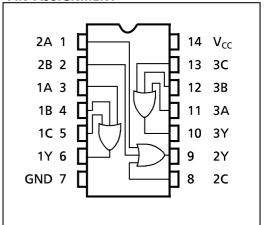
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### **FEATURES:**

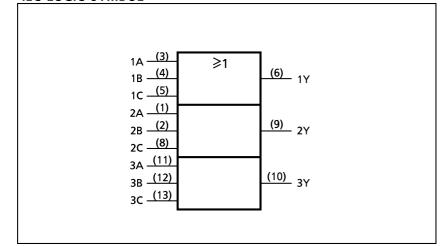
- High Speed······ $t_{pd}$  = 8ns(typ.) at  $V_{CC}$  = 5V
- Low Power Dissipation ············ $I_{CC} = 2\mu A(Max.)$  at  $Ta = 25^{\circ}C$
- High Noise Immunity  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Output Drive Capability ...... 10 LSTTL Loads
- Symmetrical Output Impedance  $| I_{OH} | = I_{OL} = 4mA(Min.)$
- Balanced Propagation Delays  $\cdots t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range···· V<sub>CC</sub> (opr.) = 2V~6V
- Pin and Function Compatible with 4075B



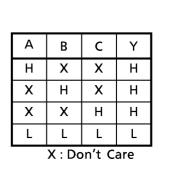
#### **PIN ASSIGNMENT**



# **IEC LOGIC SYMBOL**



#### TRUTH TABLE



#### **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V <sub>cc</sub>	<b>−</b> 0.5~7	V
DC Input Voltage	VIN	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> +0.5	V
Input Diode Current	I <sub>IK</sub>	± 20	mA
Output Diode Current	I <sub>OK</sub>	± 20	mA
DC Output Current	I <sub>OUT</sub>	± 25	mA
DC V <sub>CC</sub> / Ground Current	I <sub>cc</sub>	± 50	mA
Power Dissipation	P <sub>D</sub>	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T <sub>stg</sub>	<b>−65~150</b>	°C

<sup>\*500</sup>mW in the range of Ta=  $-40^{\circ}\text{C}\sim65^{\circ}\text{C}$ . From Ta=65°C to 85°C a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  shall be applied until 300mW.

#### **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V <sub>cc</sub>	2~6	٧
Input Voltage	V <sub>IN</sub>	0∼V <sub>cc</sub>	٧
Output Voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	<b>−40~85</b>	°C
Input Rise and Fall Time	t <sub>r</sub> , t <sub>f</sub>	$0 \sim 1000 (V_{CC} = 2.0V)$ $0 \sim 500 (V_{CC} = 4.5V)$ $0 \sim 400 (V_{CC} = 6.0V)$	ns

#### DC ELECTRICAL CHARACTERISTICS

DADAMETED	CVARDOL	TEST CONDITION		V <sub>cc</sub>	Ta = 25°C		$Ta = -40 \sim 85^{\circ}C$		UNIT	
PARAMETER SYMB		. TEST CONDITION		(v)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High - Level Input Voltage	VIH			2.0 4.5 6.0	1.50 3.15 4.20	_ 	_ _ _	1.50 3.15 4.20		v
Low - Level Input Voltage	VIL			2.0 4.5 6.0			0.50 1.35 1.80	_ _ _	0.50 1.35 1.80	v
High - Level Output Voltage	V <sub>OH</sub>	$V_{OH}$ $V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20\mu A$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	_ _ _	1.9 4.4 5.9		V
			$I_{OH} = -4 \text{ mA}$ $I_{OH} = -5.2 \text{ mA}$	4.5 6.0	4.18 5.68	4.31 5.80	_	4.13 5.63	_	
Low - Level Output Voltage	V <sub>OL</sub>	V <sub>1 N</sub> =	I <sub>OL</sub> = 20μΑ	2.0 4.5 6.0	_ _ _	0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	v
	$V_{IH}$ or $V_{IL}$	$I_{OL} = 4  mA$ $I_{OL} = 5.2  mA$	4.5 6.0	1 1	0.17 0.18	0.26 0.26	_ _	0.33 0.33		
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		6.0	1	ı	± 0.1	_	± 1.0	
Quiescent Supply Current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		6.0	_	_	1.0	_	10.0	μΑ

## AC ELECTRICAL CHARACTERISTICS ( $C_L = 15pF$ , $V_{CC} = 5V$ , Ta = 25°C, Input $t_r = t_f = 6ns$ )

		-	-			
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t <sub>TLH</sub> t <sub>THL</sub>		_	4	8	
Propagation Delay Time	t <sub>pLH</sub> t <sub>pHL</sub>		_	8	15	ns

## AC ELECTRICAL CHARACTERISTICS ( $C_L = 50pF$ , Input $t_r = t_f = 6ns$ )

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C		-	Ta = −40~85°C		UNIT
			$V_{CC}(V)$	MIN.	TYP.	MAX.	MIN.	MAX.	
	t <sub>TLH</sub>		2.0	_	30	75	_	95	
Output Transition Time			4.5	_	8	15	_	19	
· '	t <sub>THL</sub>		6.0	_	7	13	_	16	
	<b>+</b>		2.0	_	35	90	_	115	ns
Propagation Delay Time	t <sub>pLH</sub>		4.5	_	11	18	_	23	
	t <sub>pHL</sub>		6.0	_	9	15	_	20	
Input Capacitance	C <sub>IN</sub>			_	5	10	_	10	2
Power Dissipation Capacitance	C <sub>PD</sub> (1)			_	27	_	_	_	pF

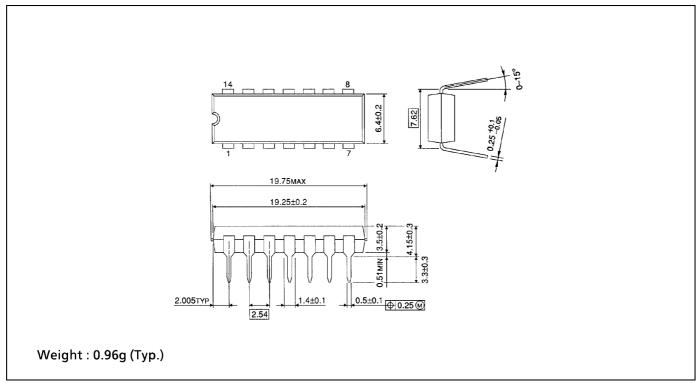
Note (1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 3$  (per Gate)

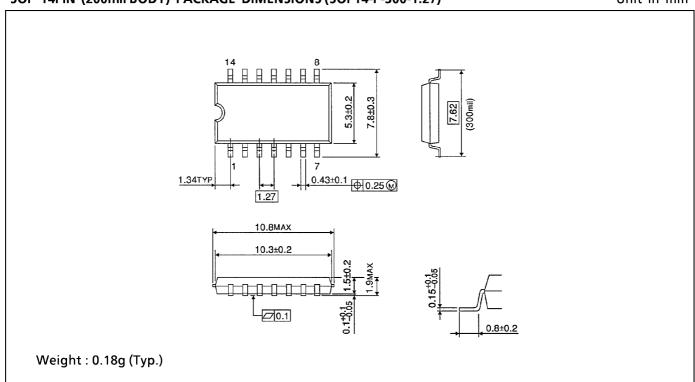
## **DIP 14PIN PACKAGE DIMENSIONS (DIP14-P-300-2.54)**

Unit in mm



## SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

Unit in mm



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